



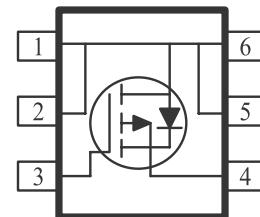
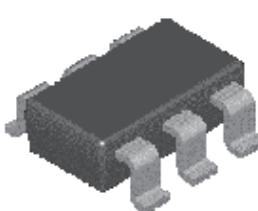
## P-Channel 20-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low  $r_{DS(on)}$  and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

- Low  $r_{DS(on)}$  provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe TSOP-6 saves board space
- Fast switching speed
- High performance trench technology

### PRODUCT SUMMARY

$V_{DS}$ (V)	$r_{DS(on)}$ m( $\Omega$ )	$I_D$ (A)
-20	90 @ $V_{GS} = -4.5V$	-2.9
	130 @ $V_{GS} = -2.5V$	-2.5
	150 @ $V_{GS} = -1.8V$	-2.3



### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ C$ UNLESS OTHERWISE NOTED)

Parameter	Symbol	Maximum	Units
Drain-Source Voltage	$V_{DS}$	-20	V
Gate-Source Voltage	$V_{GS}$	$\pm 12$	
Continuous Drain Current <sup>a</sup>	$I_D$	-2.9	A
		-2.4	
Pulsed Drain Current <sup>b</sup>	$I_{DM}$	$\pm 16$	
Continuous Source Current (Diode Conduction) <sup>a</sup>	$I_S$	-1.0	A
Power Dissipation <sup>a</sup>	$P_D$	2.0	W
		1.3	
Operating Junction and Storage Temperature Range	$T_J, T_{stg}$	-55 to 150	°C

### THERMAL RESISTANCE RATINGS

Parameter	Symbol	Maximum	Units
Maximum Junction-to-Ambient <sup>a</sup>	$R_{\theta JA}$	62.5	°C/W
		110	°C/W

#### Notes

- Surface Mounted on 1" x 1" FR4 Board.
- Pulse width limited by maximum junction temperature

<b>SPECIFICATIONS (<math>T_A = 25^\circ\text{C}</math> UNLESS OTHERWISE NOTED)</b>						
<b>Parameter</b>	<b>Symbol</b>	<b>Test Conditions</b>	<b>Limits</b>			<b>Unit</b>
			<b>Min</b>	<b>Typ</b>	<b>Max</b>	
<b>Static</b>						
Gate-Threshold Voltage	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}, I_D = -250 \mu\text{A}$	-0.7			
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 12 \text{ V}$			$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = -16 \text{ V}, V_{GS} = 0 \text{ V}$			-1	uA
		$V_{DS} = -16 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 55^\circ\text{C}$			-5	
On-State Drain Current <sup>A</sup>	$I_{D(\text{on})}$	$V_{DS} = -4.5 \text{ V}, V_{GS} = -4.5 \text{ V}$	-10			A
Drain-Source On-Resistance <sup>A</sup>	$r_{DS(\text{on})}$	$V_{GS} = -4.5 \text{ V}, I_D = -3.3 \text{ A}$			90	mΩ
		$V_{GS} = -2.5 \text{ V}, I_D = -2.9 \text{ A}$			130	
		$V_{GS} = -1.8 \text{ V}, I_D = -2.3 \text{ A}$			150	
Forward Tranconductance <sup>A</sup>	$g_{fs}$	$V_{DS} = -10 \text{ V}, I_D = -4.9 \text{ A}$		8.0		S
Diode Forward Voltage	$V_{SD}$	$I_S = 1.7 \text{ A}, V_{GS} = 0 \text{ V}$		-0.8		V
<b>Dynamic<sup>b</sup></b>						
Total Gate Charge	$Q_g$	$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V}, I_D = -4.9 \text{ A}$		8		nC
Gate-Source Charge	$Q_{gs}$			1.8		
Gate-Drain Charge	$Q_{gd}$			1.9		
Turn-On Delay Time	$t_{d(\text{on})}$	$V_{DD} = -10 \text{ V}, R_L = 6 \Omega, I_D = -1 \text{ A}, VGEN = -4.5 \text{ V}$		22		nS
Rise Time	$t_r$			35		
Turn-Off Delay Time	$t_{d(\text{off})}$			45		
Fall-Time	$t_f$			25		

## Notes

- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

## Typical Electrical Characteristics

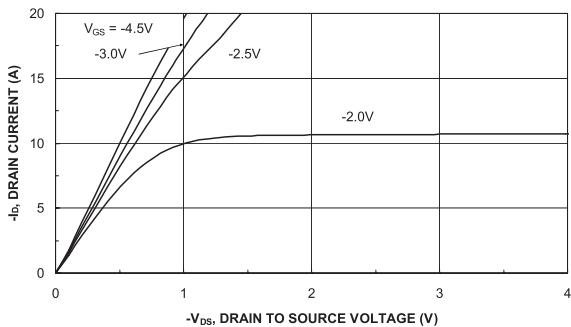


Figure 1. Output Characteristics

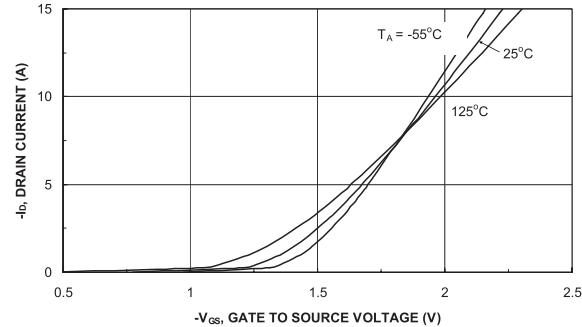


Figure 2. Transfer Characteristics

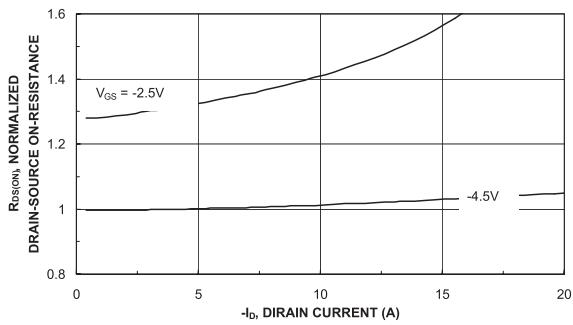


Figure 3. On-Resistance vs. Drain Current

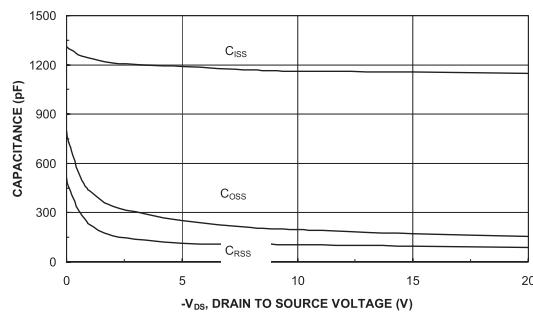


Figure 4. Capacitance

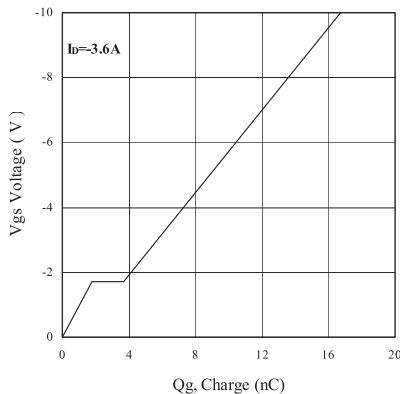


Figure 5. Gate Charge

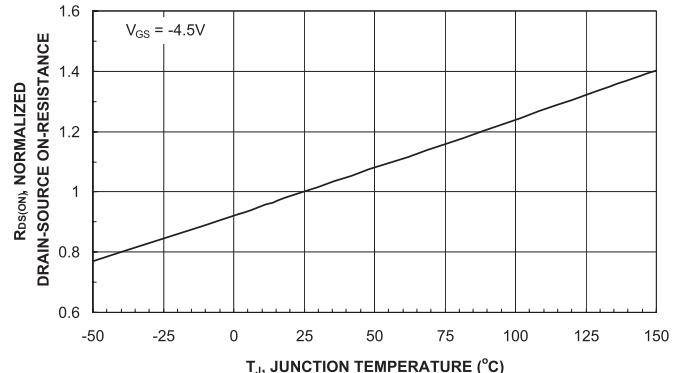
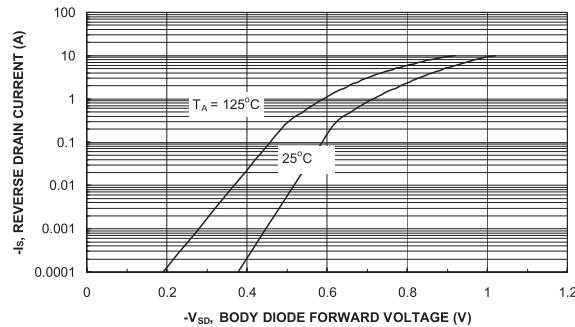
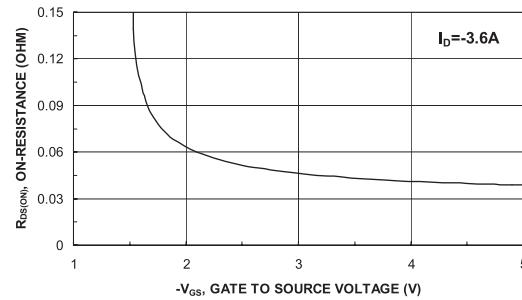


Figure 6. On-Resistance vs. Junction Temperature

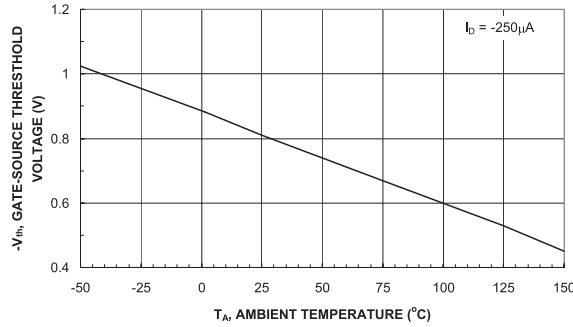
## Typical Electrical Characteristics



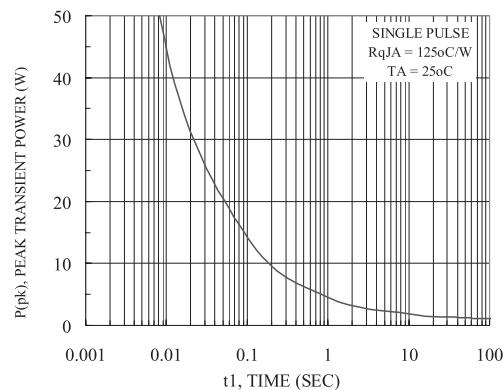
**Figure 7. Source-Drain Diode Forward Voltage**



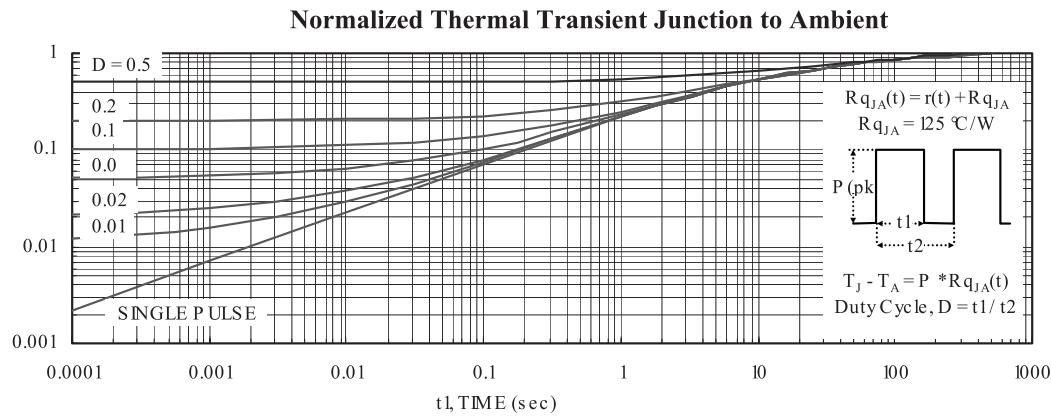
**Figure 8. On-Resistance with Gate to Source Voltage**



**Figure 9. Vth Gate to Source Voltage Vs Temperature**



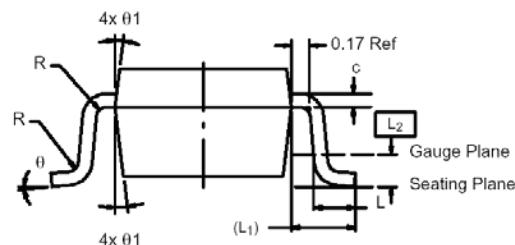
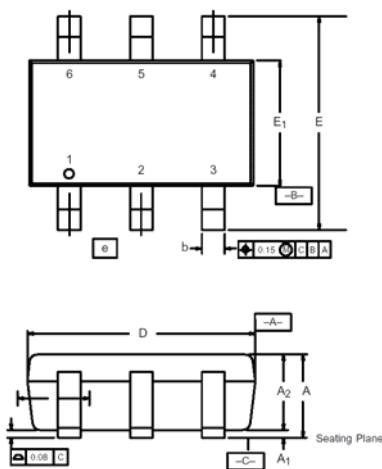
**Figure 10. Single Pulse Maximum Power Dissipation**



**Figure 11. Transient Thermal Response Curve**

## Package Information

## TSOP-6: 6LEAD



Dim	MILLIMETERS			INCHES		
	Min	Nom	Max	Min	Nom	Max
<b>A</b>	0.91	—	1.10	0.036	—	0.043
<b>A<sub>1</sub></b>	0.01	—	0.10	0.0004	—	0.004
<b>A<sub>2</sub></b>	0.84	—	1.00	0.033	0.038	0.039
<b>b</b>	0.30	0.32	0.45	0.012	0.013	0.018
<b>c</b>	0.10	0.15	0.20	0.004	0.006	0.008
<b>D</b>	2.95	3.05	3.10	0.116	0.120	0.122
<b>E</b>	2.70	2.85	2.98	0.106	0.112	0.117
<b>E<sub>1</sub></b>	1.55	1.65	1.70	0.061	0.065	0.067
<b>e</b>	1.00 BSC			0.0394 BSC		
<b>L</b>	0.35	—	0.50	0.014	—	0.020
<b>L<sub>1</sub></b>	0.60 Ref			0.024 Ref		
<b>L<sub>2</sub></b>	0.25 BSC			0.010 BSC		
<b>R</b>	0.10	—	—	0.004	—	—
$\theta$	0°	4°	8°	0°	4°	8°
$\theta_1$	7° Nom			7° Nom		